

## Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
-20V	1.9Ω @ V <sub>GS</sub> = -4.5V	-0.36A
	2.4Ω @ V <sub>GS</sub> = -2.5V	-0.32A
	3.4Ω @ V <sub>GS</sub> = -1.8V	-0.27A
	5.0Ω @ V <sub>GS</sub> = -1.5V	-0.22A

## Features and Benefits

- Low On-Resistance
- Low Input/Output Leakage
- Fast Switching Speed
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Description and Applications

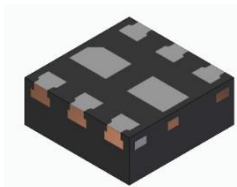
This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- Backlighting
- Load switches

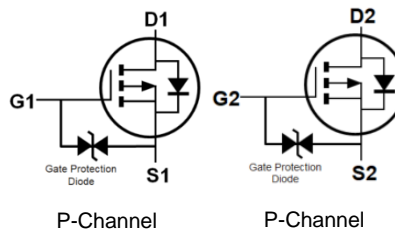
## Mechanical Data

- Package: X2-DFN1010-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 **Ⓔ4**
- Weight: 0.0015 grams (Approximate)

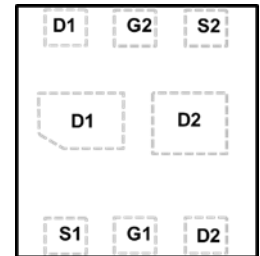
X2-DFN1010-6 (Type UXC)



Bottom View



Equivalent Circuit




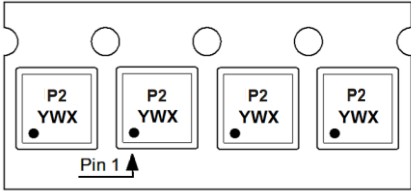
Pinout Top View

## Ordering Information (Note 4)

Orderable Part Number	Package	Tape Width (mm)	Tape Pitch (mm)	Packing	
				Qty.	Carrier
DMP22D5UDR4-7	X2-DFN1010-6 (Type UXC)	8	4	5,000	Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

DMP22D5UDR4-7		<p>P2 = Product Type Marking Code          YWX = Date Code Marking          Y = Year (ex: 4 = 2024)          W = Week (ex: a = Week 27; z Represents Week 52 and 53)          X = Internal Code (ex: U = Monday)</p>
		

### Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3

Week	1-26	27-52	53
Code	A-Z	a-z	z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Y	Z

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-20	V
Gate-Source Voltage	V <sub>GSS</sub>	±8	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	I <sub>D</sub>	T <sub>A</sub> = +25°C	-0.36
		T <sub>A</sub> = +70°C	-0.29
Maximum Continuous Body Diode Forward Current (Note 5)	I <sub>S</sub>	-0.3A	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-0.8	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P <sub>D</sub>	0.38	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	328	°C/W
Total Power Dissipation (Note 6)	P <sub>D</sub>	0.66	W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	190	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
  6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 7)</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA
Zero Gate Voltage Drain Current @T <sub>C</sub> = +25°C	I <sub>DSS</sub>	—	—	-1	μA	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±10	μA	V <sub>GS</sub> = ±5V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS (Note 7)</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	—	-1.0	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250μA
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	1.6	1.9	Ω	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -100mA
		—	2.2	2.4		V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -50mA
		—	3.2	3.4		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -20mA
		—	4.1	5.0		V <sub>GS</sub> = -1.5V, I <sub>D</sub> = -10mA
Diode Forward Voltage	V <sub>SD</sub>	—	-0.75	-1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -10mA
<b>DYNAMIC CHARACTERISTICS (Note 8)</b>						
Input Capacitance	C <sub>iss</sub>	—	17	—	pF	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	C <sub>oss</sub>	—	4.1	—		
Reverse Transfer Capacitance	C <sub>rss</sub>	—	2.7	—		
Total Gate Charge	Q <sub>g</sub>	—	0.3	—	nC	V <sub>GS</sub> = -4.5V, V <sub>DS</sub> = -10V I <sub>D</sub> = -250mA
Gate-Source Charge	Q <sub>gs</sub>	—	0.04	—		
Gate-Drain Charge	Q <sub>gd</sub>	—	0.1	—		
Turn-On Delay Time	t <sub>D(ON)</sub>	—	7.3	—	ns	V <sub>DD</sub> = -15V, V <sub>GS</sub> = -4.5V R <sub>G</sub> = 2Ω, I <sub>D</sub> = -200mA
Turn-On Rise Time	t <sub>r</sub>	—	20.7	—		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	185	—		
Turn-Off Fall Time	t <sub>f</sub>	—	97	—		

Notes: 7. Short duration pulse test used to minimize self-heating effect.  
8. Guaranteed by design. Not subject to production testing.

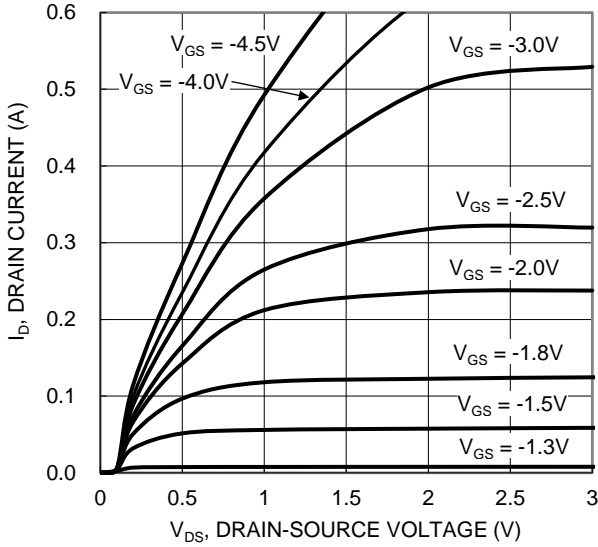


Figure 1. Typical Output Characteristic

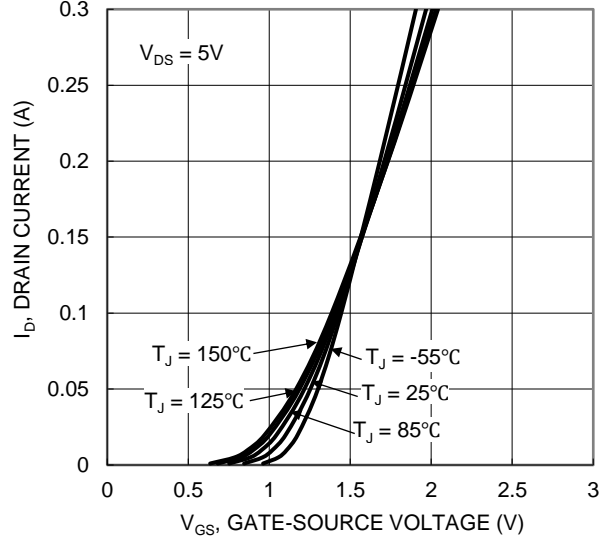


Figure 2. Typical Transfer Characteristic

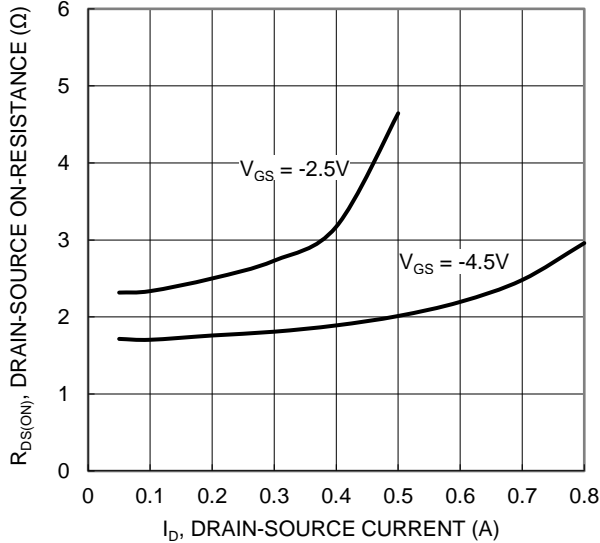


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

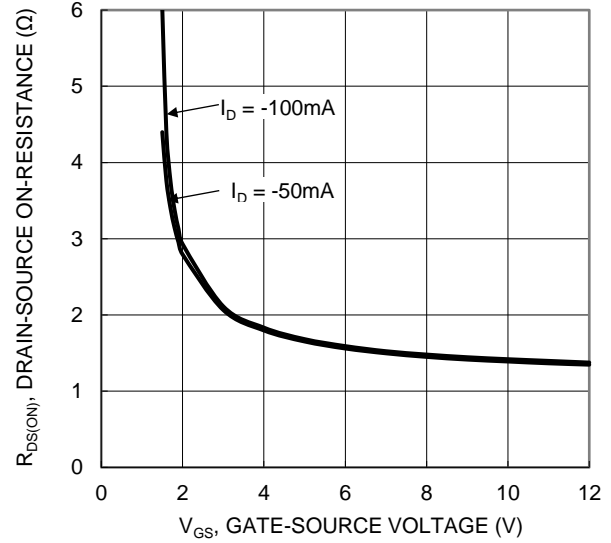


Figure 4. Typical Transfer Characteristic

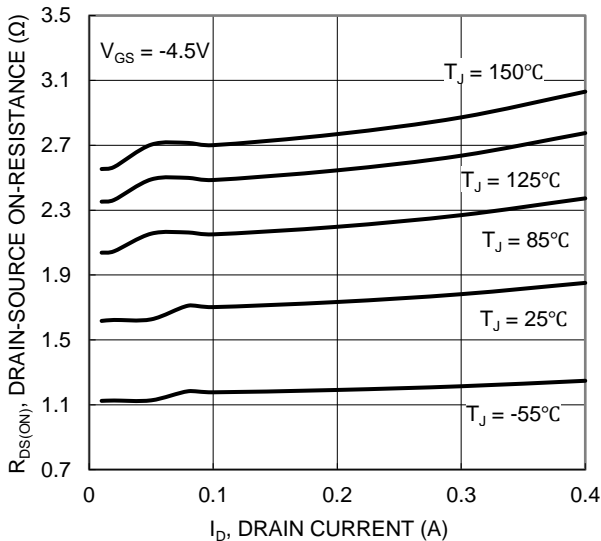


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

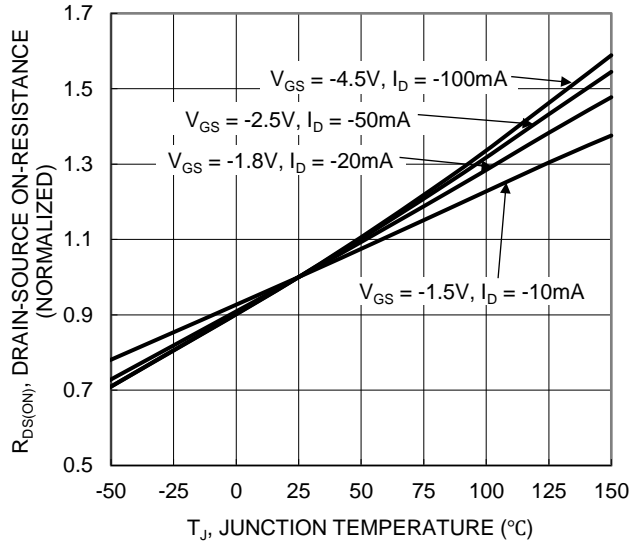


Figure 6. On-Resistance Variation with Junction Temperature

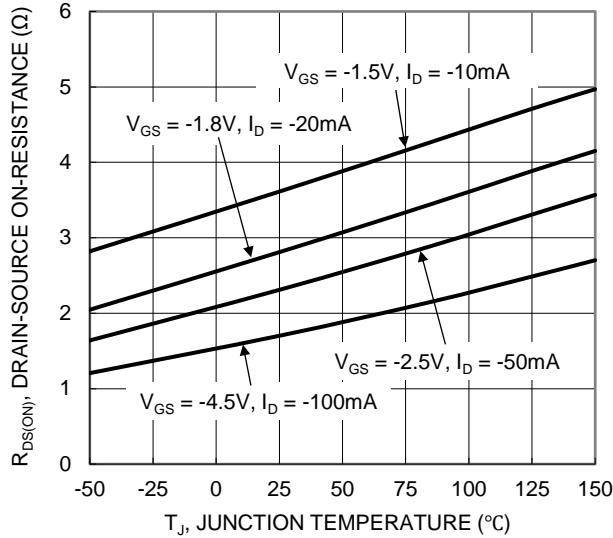


Figure 7. On-Resistance Variation with Junction Temperature

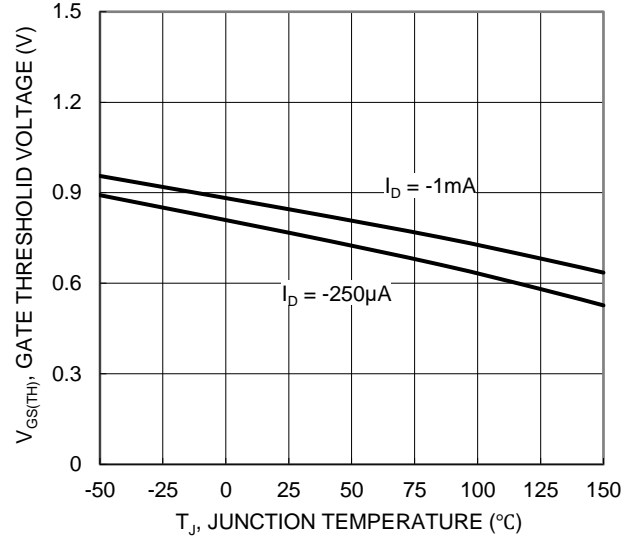


Figure 8. Gate Threshold Variation vs. Junction Temperature

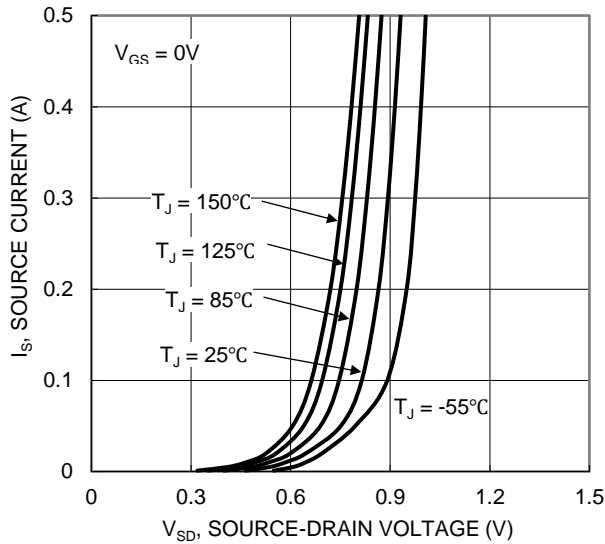


Figure 9. Diode Forward Voltage vs. Current

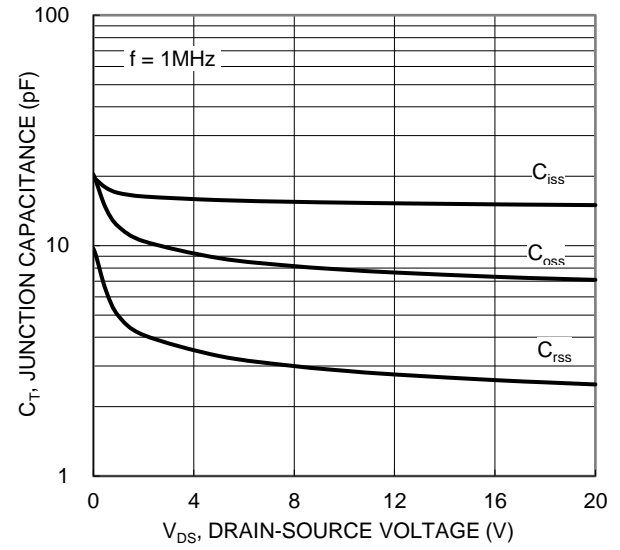


Figure 10. Typical Junction Capacitance

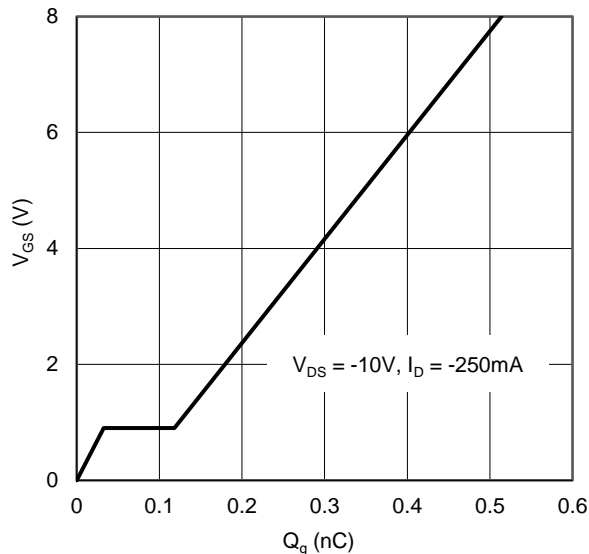


Figure 11. Gate Charge

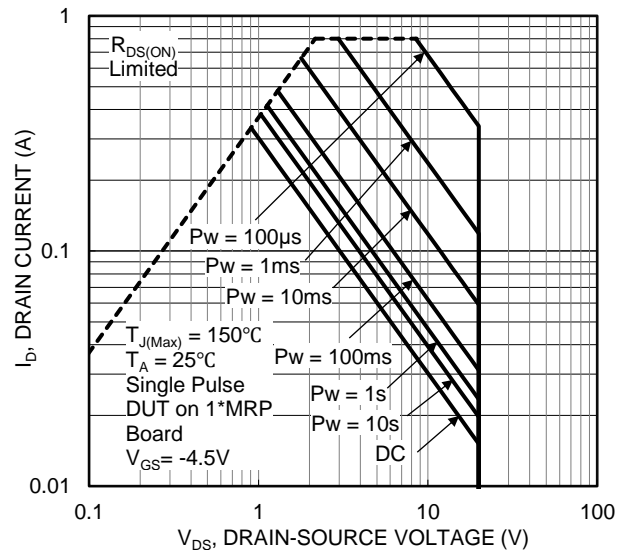


Figure 12. SOA, Safe Operation Area

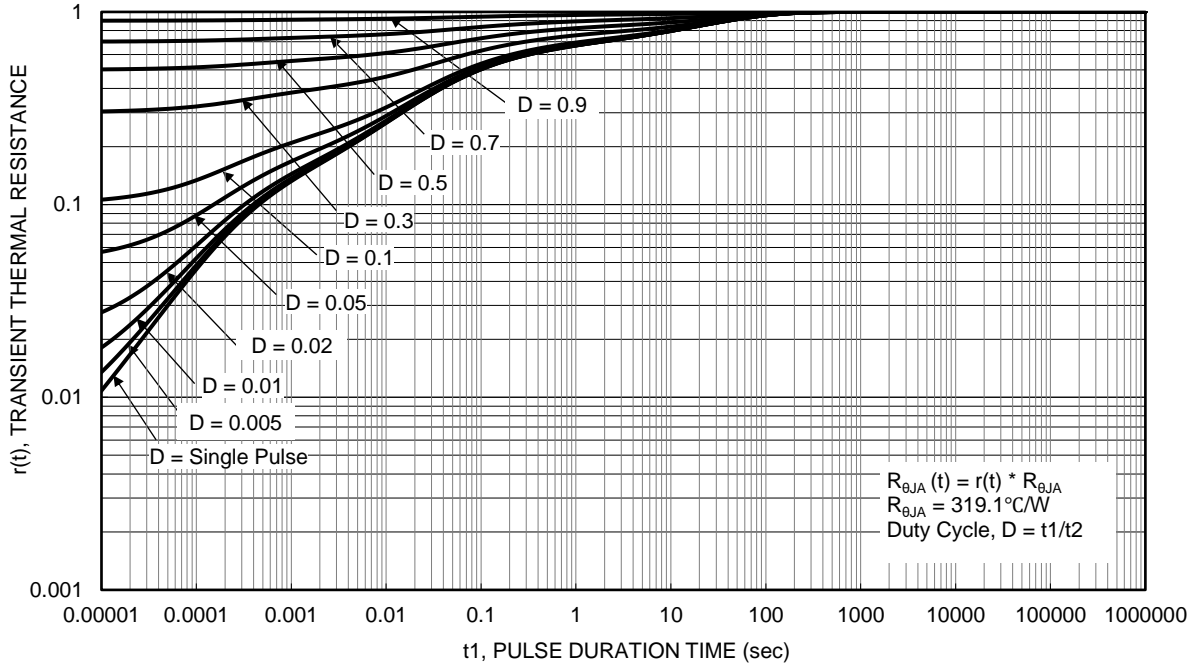
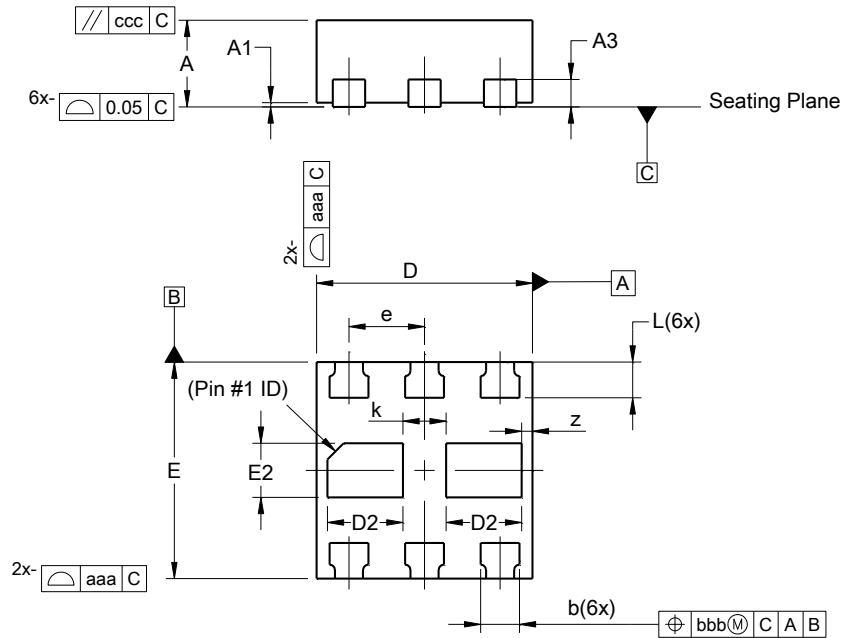


Figure 13. Transient Thermal Resistance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X2-DFN1010-6 (Type UXC)**

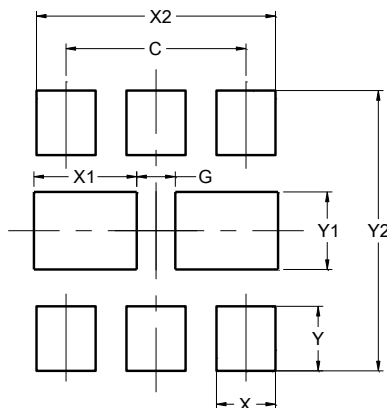


X2-DFN1010-6 (Type UXC)			
Dim	Min	Max	Typ
A	--	0.40	0.39
A1	--	0.05	--
A3	--	--	0.127
b	0.13	0.23	0.18
D	0.95	1.05	1.00
D2	0.30	0.40	0.35
E	0.95	1.05	1.00
E2	0.20	0.30	0.25
e	0.350 BSC		
L	0.115	0.215	0.165
k	--	--	0.20
z	0.02	0.08	0.05
aaa	0.08		
bbb	0.07		
ccc	0.05		
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X2-DFN1010-6 (Type UXC)**



Dimensions	Value (in mm)
C	0.700
G	0.300
X	0.230
X1	0.450
X2	0.930
Y	0.250
Y1	0.300
Y2	1.085

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